



FDH5500_F085

N-Channel UltraFET Power MOSFET

55V, 75A, 7mΩ

Features

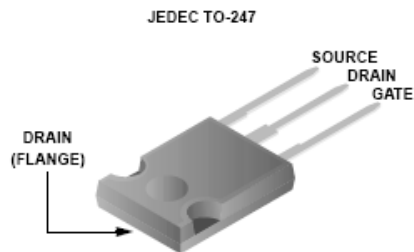
- Typ $r_{DS(on)}$ = 5.2mΩ at $V_{GS} = 10V$, $I_D = 75A$
- Typ $Q_{g(10)}$ = 118nC at $V_{GS} = 10V$
- Simulation Models
 - Temperature Compensated PSPICE and SABER™ Models
- Peak Current vs Pulse Width Curve
- UIS Rating Curve
- Related Literature
 - TB334, "Guidelines for Soldering Surface Mount Componets to PC Boards"
- Qualified to AEC Q101
- RoHS Compliant

Applications

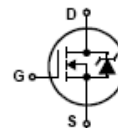
- DC Linear Mode Control
- Solenoid and Motor Control
- Switching Regulators
- Automotive Systems



Package



Symbol



MOSFET Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Ratings	Units
V_{DSS}	Drain to Source Voltage	(Note 1)	55	V
V_{DGR}	Drain to Gate Voltage ($R_{GS} = 20k\Omega$)	(Note 1)	55	V
V_{GS}	Gate to Source Voltage		± 20	V
I_D	Drain Current Continuous ($T_C < 135^\circ\text{C}$, $V_{GS} = 10\text{V}$)		75	A
	Pulsed		See Figure 4	
E_{AS}	Single Pulse Avalanche Energy	(Note 2)	864	mJ
P_D	Power Dissipation		375	W
	Dreate above 25°C		2.5	W/ $^\circ\text{C}$
T_J, T_{STG}	Operating and Storage Temperature		-55 to + 175	$^\circ\text{C}$
T_L	Max. Lead Temp. for Soldering (at 1.6mm from case for 10sec)		300	
T_{pkg}	Max. Package Temp. for Soldering (Package Body for 10sec)		260	

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance Junction to Case	0.4	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance Junction to Ambient TO-247, 1in ² copper pad area	30	$^\circ\text{C/W}$

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDH5500	FDH5500_F085	TO-247	Tube	N/A	30 units

Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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Off Characteristics

B_{VDSS}	Drain to Source Breakdown Voltage	$I_D = 250\mu\text{A}$, $V_{GS} = 0\text{V}$	55	-	-	V
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 50\text{V}$, $V_{GS} = 0\text{V}$	-	-	1	μA
		$V_{DS} = 45\text{V}$, $T_C = 150^\circ\text{C}$	-	-	250	
I_{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20\text{V}$	-	-	± 100	nA

On Characteristics

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 250\mu\text{A}$	2	2.9	4	V
$r_{DS(on)}$	Drain to Source On Resistance	$I_D = 75\text{A}$, $V_{GS} = 10\text{V}$	-	5.2	7	m Ω

Dynamic Characteristics

C_{iss}	Input Capacitance	$V_{DS} = 25\text{V}$, $V_{GS} = 0\text{V}$, $f = 1\text{MHz}$	-	3565	-	pF	
C_{oss}	Output Capacitance		-	1310	-	pF	
C_{rss}	Reverse Transfer Capacitance		-	395	-	pF	
$Q_{g(TOT)}$	Total Gate Charge at 20V	$V_{GS} = 0$ to 20V	$V_{DD} = 30\text{V}$ $I_D = 75\text{A}$ $R_L = 0.4\Omega$ $I_g = 1.0\text{mA}$	-	206	268	nC
$Q_{g(10)}$	Total Gate Charge at 10V	$V_{GS} = 0$ to 10V		-	118	153	nC
$Q_{g(TH)}$	Threshold Gate Charge	$V_{GS} = 0$ to 2V		-	6.2	8.1	nC
Q_{gs}	Gate to Source Gate Charge			-	17.8	-	nC
Q_{gd}	Gate to Drain "Miller" Charge			-	51	-	nC

Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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Switching Characteristics

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
t_{on}	Turn-On Time	$V_{DD} = 30\text{V}, I_D = 75\text{A},$ $R_L = 0.4\Omega, V_{GS} = 10\text{V},$ $R_{GS} = 2.5\Omega$	-	-	185	ns
$t_{d(on)}$	Turn-On Delay Time		-	13.7	-	ns
t_r	Rise Time		-	102	-	ns
$t_{d(off)}$	Turn-Off Delay Time		-	34	-	ns
t_f	Fall Time		-	22	-	ns
t_{off}	Turn-Off Time		-	-	91	ns

Drain-Source Diode Characteristics

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
V_{SD}	Source to Drain Diode Voltage	$I_{SD} = 75\text{A}$	-	1	1.25	V
t_{rr}	Reverse Recovery Time	$I_F = 75\text{A}, dI_{SD}/dt = 100\text{A}/\mu\text{s}$	-	60	78	ns
Q_{rr}	Reverse Recovery Charge		-	77	100	nC

Notes:

- 1: Starting $T_J = 25^\circ\text{C}$ to 175°C .
- 2: Starting $T_J = 25^\circ\text{C}$, $L = 0.48\text{mH}$, $I_{AS} = 60\text{A}$

This product has been designed to meet the extreme test conditions and environment demanded by the automotive industry. For a copy of the requirements, see AEC Q101 at: <http://www.aecouncil.com/>
 All Fairchild Semiconductor products are manufactured, assembled and tested under ISO9000 and QS9000 quality systems certification.

Typical Characteristics

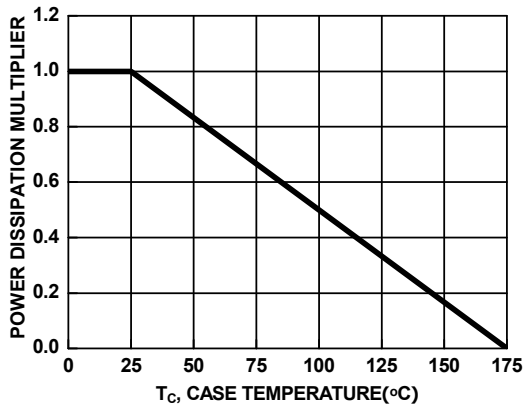


Figure 1. Normalized Power Dissipation vs Case Temperature

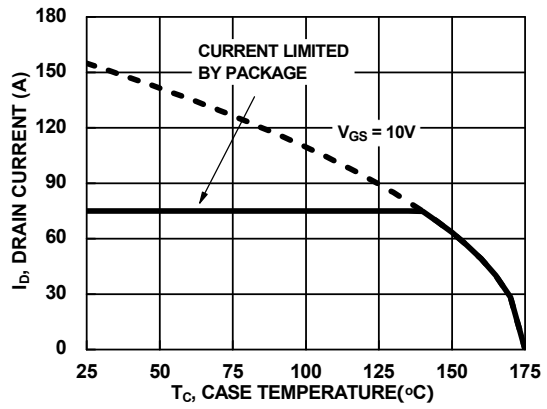


Figure 2. Maximum Continuous Drain Current vs Case Temperature

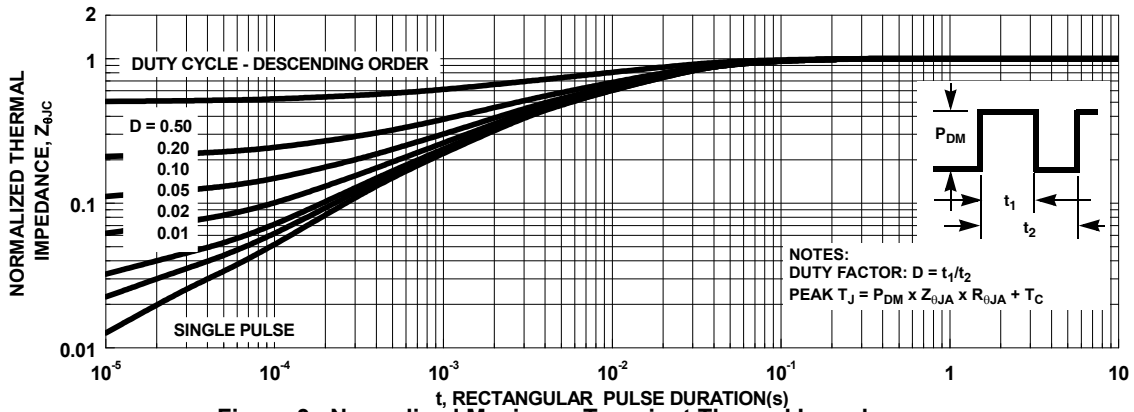


Figure 3. Normalized Maximum Transient Thermal Impedance

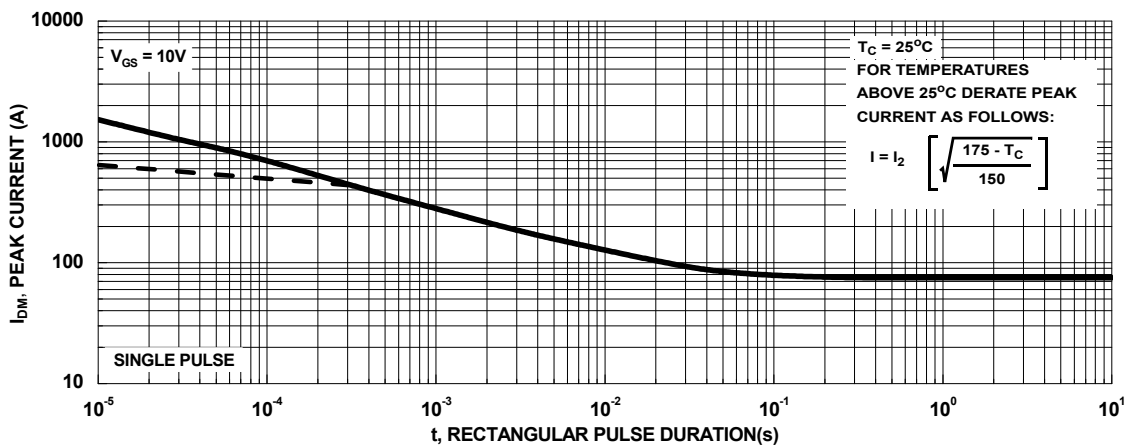


Figure 4. Peak Current Capability

Typical Characteristics

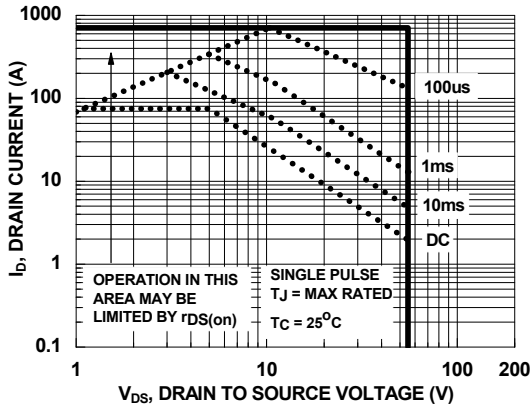
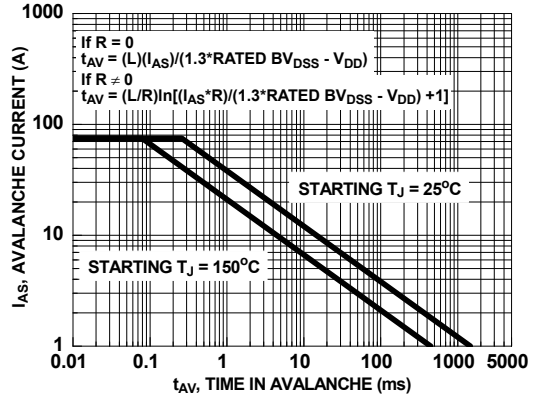


Figure 5. Forward Bias Safe Operating Area



NOTE: Refer to Fairchild Application Notes AN7514 and AN7515
Figure 6. Unclamped Inductive Switching Capability

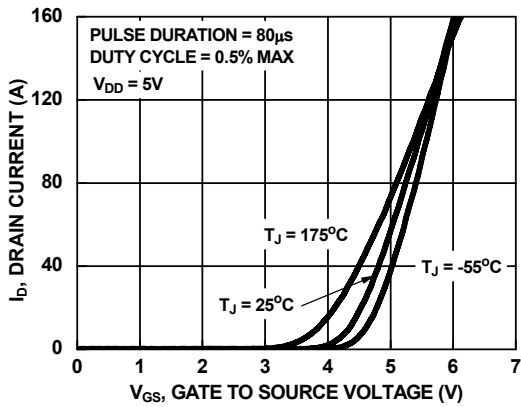


Figure 7. Transfer Characteristics

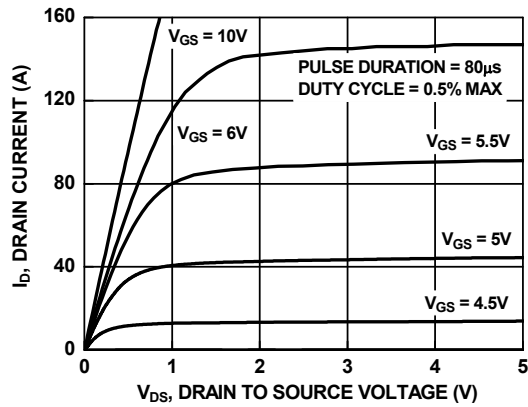


Figure 8. Saturation Characteristics

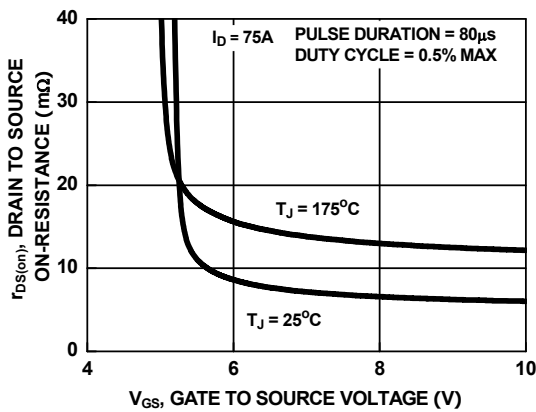


Figure 9. Drain to Source On-Resistance Variation vs Gate to Source Voltage

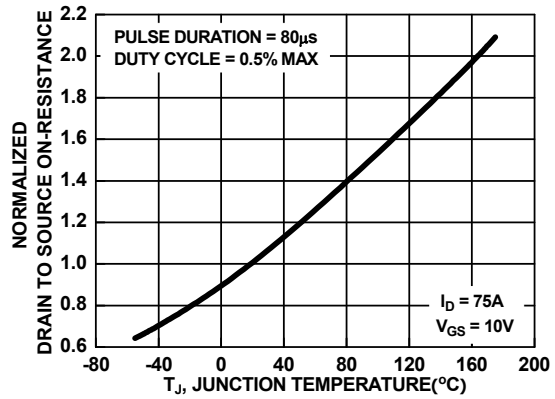


Figure 10. Normalized Drain to Source On-Resistance vs Junction Temperature

Typical Characteristics

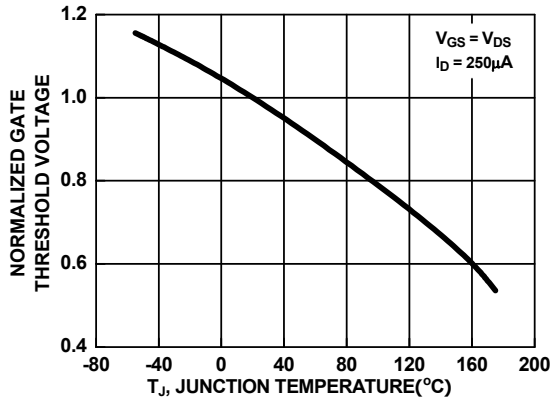


Figure 11. Normalized Gate Threshold Voltage vs Junction Temperature

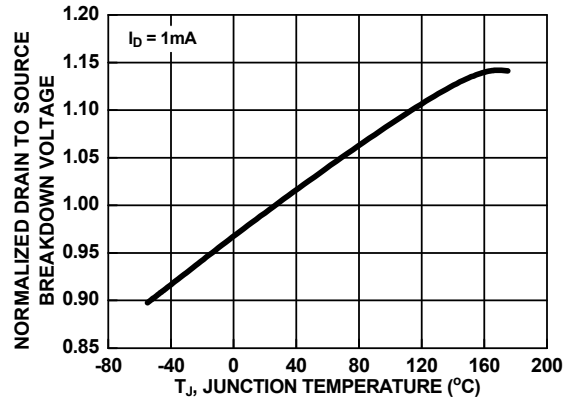


Figure 12. Normalized Drain to Source Breakdown Voltage vs Junction Temperature

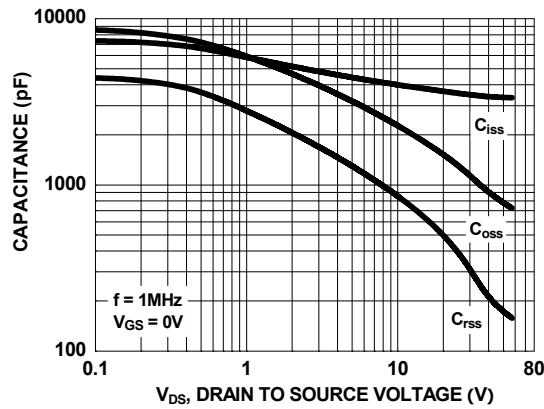


Figure 13. Capacitance vs Drain to Source Voltage

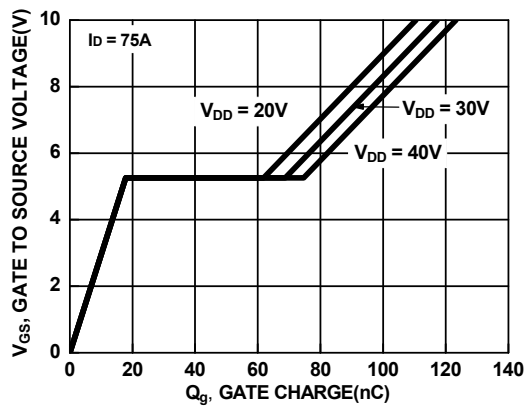



Figure 14. Gate Charge vs Gate to Source Voltage

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